BIRLA INSTITUTE OF TECHNOLOGY, MESRA, RANCHI (MID SEMESTER EXAMINATION)

CLASS: BTECH SEMESTER: V BRANCH: EEE SESSION: MO/2022 SUBJECT: EE357 ELECTRONIC DEVICES AND ANALOG CIRCUITS TIME: 2 HOURS FULL MARKS: 25 **INSTRUCTIONS:** 1. The total marks of the questions are 25. 2. Candidates attempt for all 25 marks. 3. Before attempting the question paper, be sure that you have got the correct question paper. 4. The missing data, if any, may be assumed suitably. 5. Tables/Data hand book/Graph paper etc. to be supplied to the candidates in the examination hall. _____ CO ΒL 01 (a) What is diffusion capacitance? [2] CO1,CO2 L1 Q1 Prove that transition capacitance $C_T = \epsilon A/W$ [3] CO1,CO2 L2 (b) Q2 (a) Find out the ripple factor of half wave rectifier. CO1,CO2 L2 [2] [3] Q2 CO1,CO2 L3 (b) **R1** Vin

Given that: R1-220 ohm, V_Z =20V,

 $I_{\text{ZM}}\text{=}60\text{mA},\,R_{\text{L}}\text{=}1.2\text{kohm},\,\text{Find}$ the range of Vin.

RL

D1

Q3 Q3	(a) (b)	What are the advantages and disadvantages of LED. In a half wave rectifier diode resistance= 10 ohm load resistance= 100ohm, secondary of transformer supply 50V(rms). Find (a) the peak current (b) the total input ac power (c) the DC voltage.	[2] [3]	C01,C02 C01,C02	L2 L3
Q4 Q4	(a) (b)	What are the different modes of BJT. Draw the input and output characteristics of CE configuration, also explain in brief.	[2] [3]	CO1,CO2 CO1,CO2	L2 L2
Q5	(a)	Draw the transductance curve of a JFET, also write the current equation	[2]	CO1,CO2	L2
Q5	(b)	What is IGBT? Explain its characteristics.	[3]	CO1,CO2	L2

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